

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

Monolithic Digital IC

LB11861MC

Single-Phase Full-WaveFan Motor Driver

Overview

The LB11861MC is a single-phase bipolar drive motor driver that easily implements direct PWM motor drive systems with excellent efficiency. The LB11861MC is optimal for fan motor drive in personal computer power supply systems and CPU cooling fan systems.

Features

- Single-phase full-wave drive (16V, 1.2A transistors are built in)
- External PWM control pin incorporated (f=16k to 50kHz)
 External PWM signal DUTY control to enable speed control to stop, medium speed, and full speed Slow-Decay regeneration to enable low power consumption and high-efficiency rotation control
- Soft switching circuit incorporated
 Soft-SW circuit achieving small loss, low noise, and low vibration at a time of phase shift
- •Built-in regenerative diode (Di); only requires a minimal number of external components.
- Built-in lock protection and automatic recovery circuits
- FG (speed detection) outputs incorporated
- Built-in thermal shutdown circuit.

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc., please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter Symbol | | Conditions | Ratings | Unit |
|--|----------------------|------------------------------------|-----------------|------|
| V _{CC} maximum output voltage | V _{CC} max | | 18 | V |
| OUT pin maximum output current | I _{OUT} max | | 1.2 | А |
| OUT pin output voltage | V _{OUT} max | | 18 | V |
| PWM-IN input pin voltage | VPWM-IN max | | V _{CC} | V |
| FG output pin output voltage | VFG max | | 18 | V |
| FG output current | IFG max | | 10 | mA |
| Allowable power dissipation | Pd max | When mounted on a circuit board *1 | 0.8 | W |
| Operating temperature | Topr | | -30 to +90 | °C |
| Storage temperature | Tstg | | -55 to +150 | °C |

^{*1} Specified circuit board : $114.3 \times 76.1 \times 1.6$ mm³, glass epoxy.

Recommended Operating Conditions at Ta = 25°C

| Parameter Symbol | | Conditions | Ratings | Unit |
|------------------------------------|-----------|------------|------------------------|------|
| V _{CC} supply voltage | Vcc | | 4.5 to 16 | V |
| VPWM-IN input H voltage range | VPWM-IN-H | | 2.5 to V _{CC} | V |
| VPWM-IN input L voltage range | VPWM-IN-L | | 0 to 1 | V |
| Hall sensor input common-mode VICM | | | 0.2 to 3 | V |
| input voltage range | | | | |

Electrical Characteristics Unless otherwise specified Ta = 25°C, $V_{CC} = 12V$

| | Symbol | 0 111 | Ratings | | | |
|------------------------------------|-------------------|---|---------|------|------|------|
| Parameter | | Conditions | min | typ | max | Unit |
| Circuit current | I _{CC} 1 | Drive mode | 15 | 24.5 | 29 | mA |
| | I _{CC} 2 | Lock protection mode | 6 | 11 | 16 | μΑ |
| CT pin high-level voltage | VCTH | | 3.45 | 3.6 | 3.75 | V |
| CT pin low-level voltage | VCTL | | 1.4 | 1.55 | 1.7 | V |
| ICT charge current | ICT1 | | 1.7 | 2.2 | 2.8 | μА |
| ICT discharge current | ICT2 | | 0.17 | 0.22 | 0.28 | μΑ |
| ICT charge/discharge current ratio | RCT | | 8 | 10 | 11.5 | |
| OUT output low saturation voltage | V _{OL} | I _O = 200mA | | 0.2 | 0.3 | V |
| OUT output high saturation voltage | VOH | I _O = 200mA | | 0.9 | 1.1 | V |
| Hall sensor input sensitivity | VHN | Zero peak value (including offset and hysteresis) | | 10 | 20 | mV |
| PWM-IN input current | IPIN | PWM-IN=0V | | | -10 | μΑ |
| RD/FG output pin low-level voltage | VRDL/FGL | IRD/FG = 5mA | | 0.2 | 0.3 | V |
| RD/FG output pin leakage current | IRDL/FGL | VRD/FG = 7V | | | 30 | μΑ |
| Heat protection circuit | THD | (*2) Design target | | | 180 | °C |

^(*2) The standard is a design target value and measurement with the single piece has not been made.

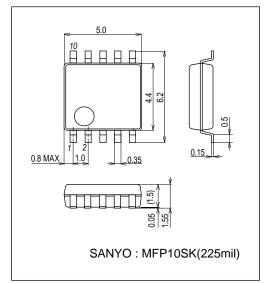
Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

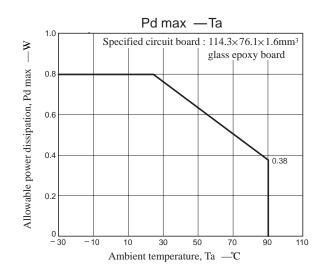
Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

Package Dimensions

unit: mm (typ)

3420

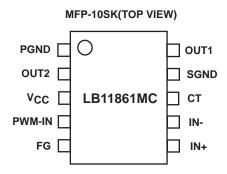




Truth Table

| PWM-IN | IN- | IN+ | СТ | OUT1 | OUT2 | FG | Mode | |
|--------|------|------|------|------|------|-----|--------------------------------|--|
| | High | Low | | High | Low | Low | Duning potentials during | |
| High | Low | High | Low | Low | High | Off | During rotation – drive | |
| Low | High | Low | | Off | Low | Low | During rotation – regeneration | |
| | Low | High | | Low | Off | Off | | |
| - | High | Low | | High | Off | Low | Land and the state of | |
| - | Low | High | High | Off | High | Off | Lock protection | |

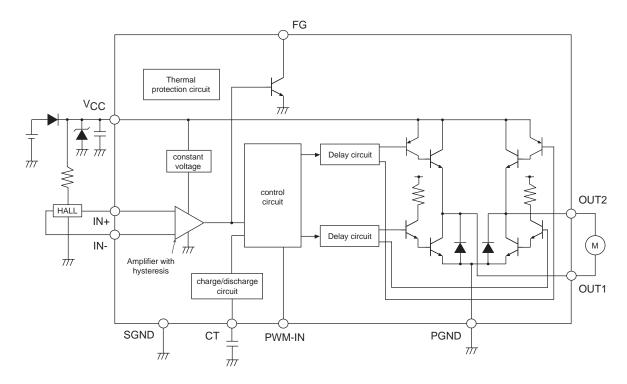
Pin Assignment



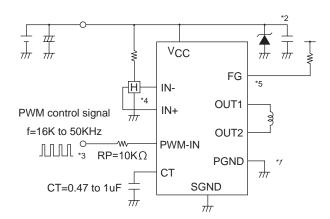
VCC: Common power supply for motor and control systems

PGND: Motor system GND SGND: Control system GND

Block Diagram



Application Circuit Example



st 1. Power supply and ground lines

P-GND is connected to the motor power supply system and S-GND is connected to the control circuit power supply system. These two systems should be formed from separate lines and the control system external components should be connected to S-GND.

st2. Regeneration power supply stabilization capacitor

The capacitor CM provides power supply stabilization for both PWM drive and kickback absorption. A capacitor with a value of over 1 to $10\mu F$ is used for CM. Insert the zenor diode for kickback protection between VCC and GND. Since this IC adopts a technique in which switching is performed by the high side transistor and regeneration is handled by the low side transistor, the pattern connecting CM to VM and P-GND must be as wide and as short as possible.

*3. PWM-IN pin

This is for speed control with the external PWM signal. With driving at the input of "H" and regeneration (Slow-Decay) at the input of "L", high efficiency rotation control can be made. $RP=10k\Omega$ is the current limiting resistor for protection. Though the input signal frequency range is 0 to 50 kHz, 16 k to 50 kHz is recommended. Rotation can be stopped by inputting "L".

LB11861MC

*4. Hall sensor input

Lines that are as short as possible must be used to prevent noise from entering the system. The Hall sensor input circuit consists of a comparator with hysteresis (20mV). We recommend that the Hall sensor input level be at least three times this hysteresis, i.e. at least 60mVp-p.

*5.FG output

This is an open collector output, and a rotation count detection function can be implemented using this FG output, which corresponds to the phase switching. This pin must be left open if unused.

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of March, 2012. Specifications and information herein are subject to change without notice.